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August 2006



FDJ1027P P-Channel 1.8V Specified PowerTrench[®] MOSFET

Features

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- Low gate charge, High Power and Current handling capability
- High performance trench technology for extremely low R_{DS(ON)}
- FLMP SC75 package: Enhanced thermal performance in industry-standard package size

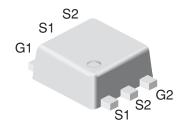
Applications

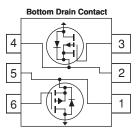
Battery management/Charger Application

Load switch

General Description

This dual P-Channel 1.8V specified MOSFET uses Fairchild's advanced low voltage PowerTrench process. Packaged in FLMP SC75, the $R_{DS(ON)}$ and thermal properties of the device are optimized for battery power management applications.





MOSFET Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-20	V
V _{GSS}	Gate-Source Voltage		±8	V
I _D	Drain Current – Continuous	(Note 1a)	-2.8	A
	– Pulsed		-12	
PD	Power Dissipation for Single Operation	(Note 1a)	1.5	W
		(Note 1b)	0.9	
T _J , T _{stg}	Operating and Storage Junction Temperature	re Range	-55 to +150	°C
Thermal Ch	aracteristics			ł
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	80	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		5	

Package Marking and Ordering Information

.G	FDJ1027P	7"	8mm	3000 units
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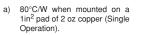
FDJ1027P
27P P-Channel 1.8V Specified PowerTrench [®] N
1.8V S
Specified
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nch [®] I
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Characte	eristics		1	1	1	1
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-13		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Characte	ristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.4	-0.8	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -2.8 \text{ A} \\ V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -2.2 \text{ A} \\ V_{GS} = -1.8 \text{ V}, \text{ I}_{D} = -1.7 \text{ A} \\ V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -2.8 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C} \end{array} $		108 163 283 150	160 230 390 238	mΩ
9 _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -2.8 \text{ A}$		5		S
Dynamic Ch	aracteristics					
C _{iss}	Input Capacitance	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$		290		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		55		pF
C _{rss}	Reverse Transfer Capacitance			29		pF
Rg	Gate Resistance	f = 1.0 MHz		13		Ω
Switching C	haracteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ A},$		8	16	ns
t _r	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, \text{ R}_{GEN} = 6 \ \Omega$		13	23	ns
t _{d(off)}	Turn–Off Delay Time			13	23	ns
t _f	Turn–Off Fall Time			18	32	ns
Qg	Total Gate Charge	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -2.8 \text{ A},$ $V_{GS} = -4.5 \text{ V}$		3	4	nC
Q _{gs}	Gate-Source Charge			0.65		nC
Q _{gd}	Gate-Drain Charge			0.75		nC
Drain-Sourc	e Diode Characteristics and Maximu	m Ratings				
I _S	Maximum Continuous Drain-Source D	Diode Forward Current			-1.25	А
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = -1.25 \text{ A} (\text{Note 2})$		-0.8	-1.2	V
trr	Diode Reverse Recovery Time	I _F = -2.8 A,		14		ns
Qrr	Diode Reverse Recovery Charge	d _{iF} /d _t = 100 A/µs		4		nC

Notes:

1. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BJC} is guaranteed by design while R_{BCA} is determined by the user's board design.



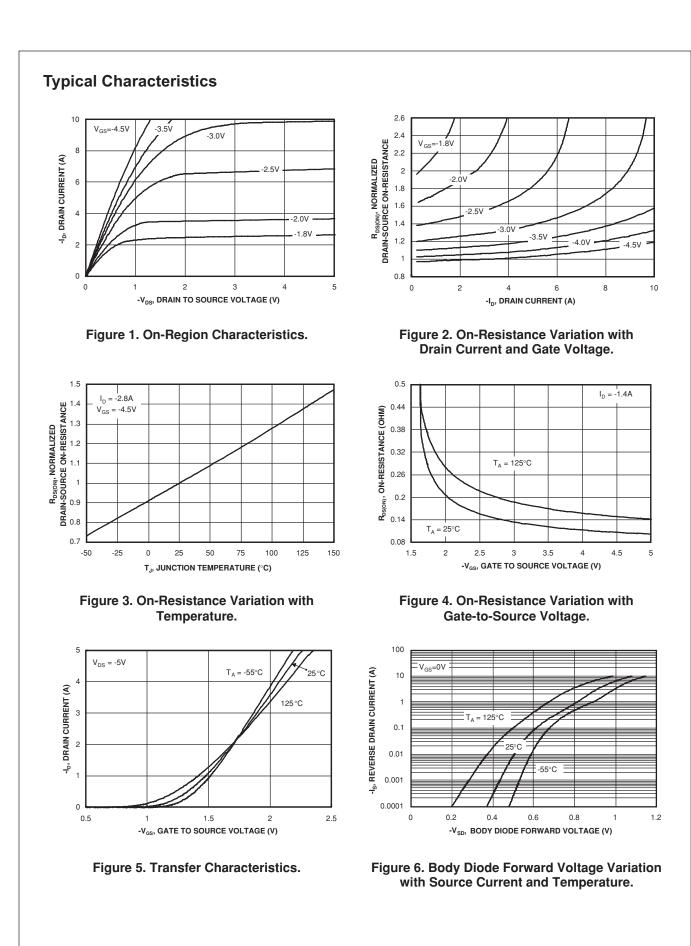


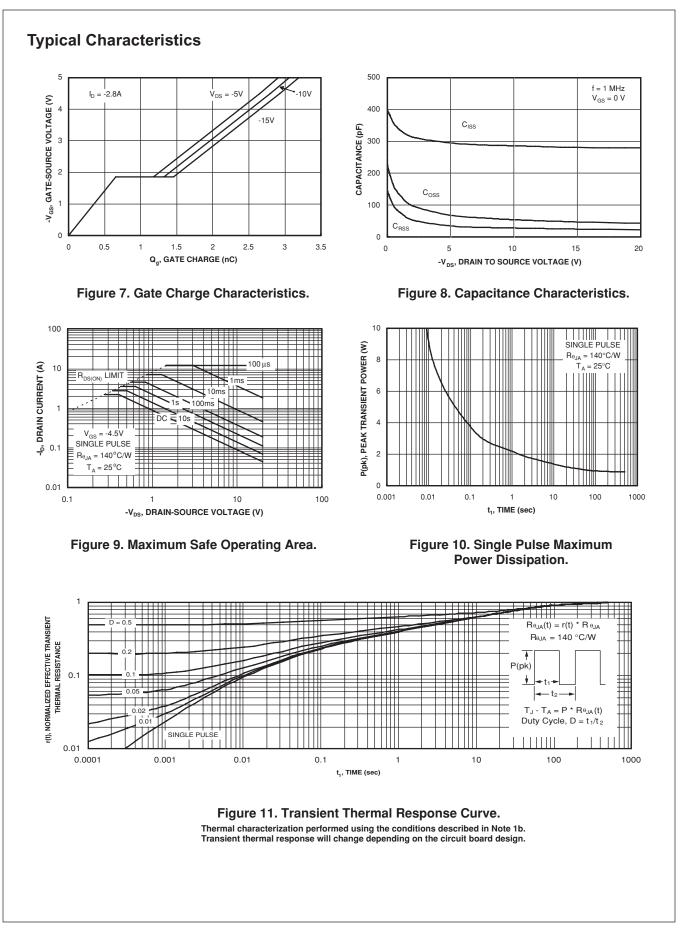


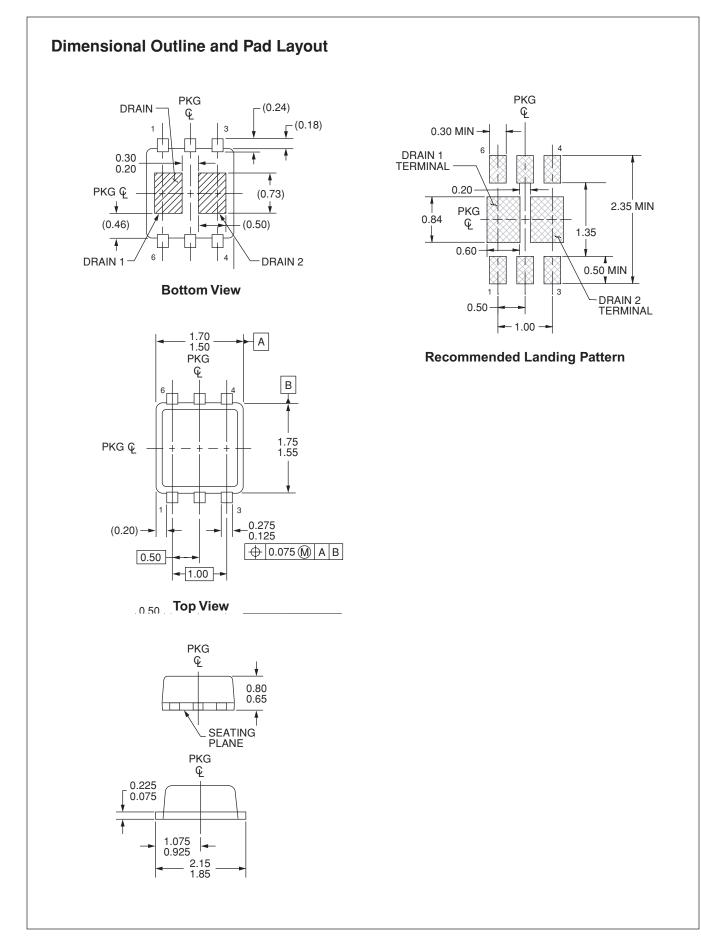
b) 140°C/W when mounted on a minimum pad of 2 oz copper (Single Operation).

2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%









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